NSN 5961-01-181-5718

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-181-5718 **Inclosure Material:** Ceramic **Overall Length:** 0.090 inches **Overall Diameter:** 0.080 inches **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 working peak reverse voltage **Current Rating Per Characteristic:** 20.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig:

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